

# bq2920x Voltage Protection with Automatic Cell Balance for 2-Series Cell Li-Ion Batteries

## 1 Features

- 2-Series Cell Secondary Protection
- Automatic Cell Imbalance Correction with External Enable Control
  - $\pm 30$ -mV Enable, 0-mV Disable Thresholds Typical
- External Capacitor-Controlled Delay Timer
- External Resistor-Controlled Cell Balance Current
- Low Power Consumption  $I_{CC} < 3 \mu A$  Typical ( $V_{CELL(ALL)} < V_{PROTECT}$ )
- Internal Cell Balancing Handles Current up to 15 mA
- External Cell Balancing Mode Supported
- High-Accuracy Overvoltage Protection:
  - $\pm 25$  mV with  $T_A = 0^\circ C$  to  $60^\circ C$
- Fixed Overvoltage Protection Thresholds: 4.30 V, 4.35 V
- Small 8L DRB Package

## 2 Applications

- 2<sup>nd</sup> Level Protection in Li-Ion Battery Packs
  - Netbook Computers
  - Power Tools
  - Portable Equipment and Instrumentation
  - Battery Backup Systems

## 3 Description

The bq2920x device is a secondary overvoltage protection IC for 2-series cell lithium-ion battery packs that incorporates a high-accuracy precision overvoltage detection circuit and automatic cell imbalance correction.

The voltage of each cell in a 2-series cell battery pack is compared to a factory programmed internal reference voltage. If either cell reaches an overvoltage condition, the OUT pin changes from low to high state.

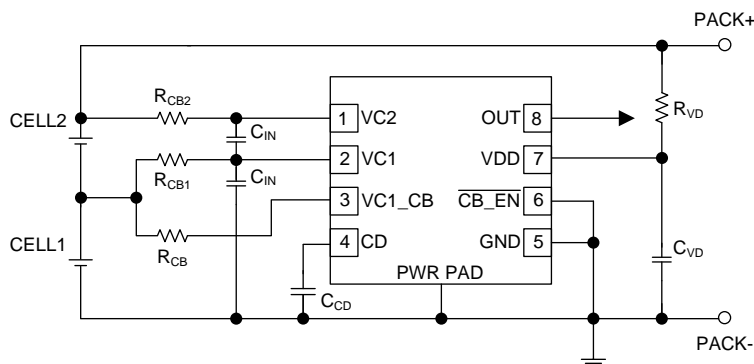
The bq2920x can perform automatic voltage-based cell imbalance correction. Balancing can start when the cell voltages are different by nominally 30 mV or more and stops when the difference is nominally 0 mV. Cell balancing is enabled and disabled by the CB\_EN pin.

### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
bq29200	VSON (8)	3.00 mm x 3.00 mm
bq29209		

(1) For all available packages, see the orderable addendum at the end of the datasheet.

### Simplified Schematic



## Table of Contents

<b>1 Features</b> .....	<b>1</b>	8.3 Feature Description .....	<b>8</b>
<b>2 Applications</b> .....	<b>1</b>	8.4 Device Functional Modes .....	<b>12</b>
<b>3 Description</b> .....	<b>1</b>	<b>9 Application and Implementation</b> .....	<b>13</b>
<b>4 Revision History</b> .....	<b>2</b>	9.1 Application Information .....	<b>13</b>
<b>5 Device Options</b> .....	<b>4</b>	9.2 Typical Applications .....	<b>13</b>
<b>6 Pin Configuration and Functions</b> .....	<b>4</b>	9.3 System Example .....	<b>14</b>
<b>7 Specifications</b> .....	<b>4</b>	<b>10 Power Supply Recommendations</b> .....	<b>14</b>
7.1 Absolute Maximum Ratings .....	<b>4</b>	<b>11 Layout</b> .....	<b>15</b>
7.2 ESD Ratings .....	<b>5</b>	11.1 Layout Guidelines .....	<b>15</b>
7.3 Recommended Operating Conditions .....	<b>5</b>	11.2 Layout Example .....	<b>15</b>
7.4 Thermal Information .....	<b>5</b>	<b>12 Device and Documentation Support</b> .....	<b>16</b>
7.5 Electrical Characteristics .....	<b>5</b>	12.1 Related Links .....	<b>16</b>
7.6 Recommended Cell Balancing Configurations .....	<b>7</b>	12.2 Community Resources .....	<b>16</b>
7.7 Typical Characteristics .....	<b>7</b>	12.3 Trademarks .....	<b>16</b>
<b>8 Detailed Description</b> .....	<b>8</b>	12.4 Electrostatic Discharge Caution .....	<b>16</b>
8.1 Overview .....	<b>8</b>	12.5 Glossary .....	<b>16</b>
8.2 Functional Block Diagram .....	<b>8</b>	<b>13 Mechanical, Packaging, and Orderable Information</b> .....	<b>16</b>

## 4 Revision History

Changes from Revision B (December 2014) to Revision C	Page
• Changed <i>Typical Application</i> title to <i>Simplified Schematic</i> .....	<b>1</b>
• Changed resistor $R_{VD}$ location, added PACK+ and PACK- in the <i>Simplified Schematic</i> image .....	<b>1</b>
• Deleted the Lead Temperature (soldering) from the <i>Absolute Maximum Ratings</i> table .....	<b>4</b>
• Deleted table notes 2 through 7 from the <i>Thermal Information</i> .....	<b>5</b>
• Changed resistor $R_{VD}$ location in <b>Figure 9</b> .....	<b>13</b>
• Added title to <b>Table 1</b> .....	<b>13</b>
• Changed resistor $R_{VD}$ location, added PACK+ and PACK- in <b>Figure 11</b> .....	<b>14</b>

Changes from Revision A (September 2010) to Revision B	Page
• Added <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section .....	<b>1</b>

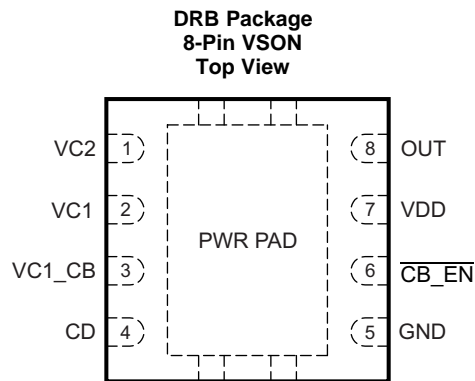
**Changes from Original (June 2010) to Revision A**
**Page**

• Changed values in $X_{\text{DELAY}}$ and $X_{\text{DELAY\_CTM}}$ electrical characteristics.....	5
• Changed specifications for $V_{\text{OUT}}$ .....	6
• Changed test conditions for $V_{\text{OUT}}$ , $I_{\text{OH}}$ , and $I_{\text{OL}}$ .....	6
• Added $V_{\text{MM\_DET\_ON}}$ : $VC2 = VDD = 7.6 \text{ V}$ .....	6
• Changed $V_{\text{MM\_DET\_OFF}}$ : From $VDD - VC2 - 7.6 \text{ V}$ to $VC2 = VDD = 7.6 \text{ V}$ .....	6
• Changed content in Recommended Cell Balancing Configurations section.....	7
• Added $I_{\text{CD}}$ Charge Current figure.....	7
• Added $I_{\text{CD}}$ Discharge Current figure.....	7
• Changed $X_{\text{DELAY}}$ from nominally $8.0 \text{ s}/\mu\text{F}$ to nominally $9.0 \text{ s}/\mu\text{F}$ .....	8
• Changed Timing for Overvoltage Sensing figure.....	9
• Added Cell Imbalance Auto-Detection (Via Cell Voltage) section.....	10
• Changed VDD value in Customer Test Mode from $8.5 \text{ V}$ to $9.5 \text{ V}$ .....	10
• Changed the Voltage Test Limits figure.....	11
• Added External Cell Balancing section.....	14

## 5 Device Options

T <sub>A</sub>	PART NUMBER	OVP
–40°C to +110°C	BQ29200	4.35 V
	BQ29209	4.30 V

## 6 Pin Configuration and Functions



**Pin Functions**

PIN		DESCRIPTION
NAME	NO.	
$\overline{\text{CB\_EN}}$	6	Cell balance enable
CD	4	Connection to external capacitor for programmable delay time
GND	5	Ground pin
OUT	8	Output
Thermal Pad	PWR PAD	GND pin to be connected to the PWRPAD on the printed circuit board for proper operation
VC1	2	Sense voltage input for bottom cell
VC1_CB	3	Cell balance input for bottom cell
VC2	1	Sense voltage input for top cell
VDD	7	Power supply

## 7 Specifications

### 7.1 Absolute Maximum Ratings

Over-operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
Supply voltage range, V <sub>MAX</sub>	VDD–GND	–0.3	16	V
Input voltage range, V <sub>IN</sub>	VC2–GND, VC1–GND	–0.3	16	V
	VC2–VC1, CD–GND	–0.3	8	V
	$\overline{\text{CB\_EN}}$ –GND	–0.3	16	V
Output voltage range, V <sub>OUT</sub>	OUT–GND	–0.3	16	V
Continuous total power dissipation, P <sub>TOT</sub>	See <a href="#">Thermal Information</a> .			
Storage temperature range, T <sub>stg</sub>		–65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 7.2 ESD Ratings

		VALUE	UNIT
V <sub>(ESD)</sub> Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions.

## 7.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
Supply voltage, VDD		4		10	V
Input voltage range VC2–VC1, VC1–GND		0		5	V
Delay time capacitance, t <sub>d(CD)</sub>	C <sub>CD</sub> (See Figure 9.)		0.1		μF
Voltage monitor filter resistance	R <sub>IN</sub> (See Figure 9.)	100	1K		Ω
Voltage monitor filter capacitance	C <sub>IN</sub> (See Figure 9.)	0.01	0.1		μF
Supply voltage filter resistance	R <sub>VD</sub> (See Figure 9.)		100	1K	Ω
Supply voltage filter capacitance	C <sub>VD</sub> (See Figure 9.)		0.1		μF
Cell balance resistance	R <sub>CB</sub> (See Figure 9 and <i>Protection (OUT) Timing</i> .)	100		4.7K	Ω
Operating ambient temperature range, T <sub>A</sub>		–40		110	°C

## 7.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		bq2920x	UNIT
		DRB	
		8 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	50.5	°C/W
R <sub>θJC(top)</sub>	Junction-to-case(top) thermal resistance	25.1	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	19.3	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	0.7	°C/W
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	18.9	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case(bottom) thermal resistance	5.2	°C/W

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

## 7.5 Electrical Characteristics

Typical values stated where T<sub>A</sub> = 25°C and VDD = 7.2 V. Minimum and maximum values stated where T<sub>A</sub> = –40°C to 110°C and VDD = 4 V to 10 V (unless otherwise noted).

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT		
V <sub>PROTECT</sub>	Overvoltage detection voltage	bq29209		4.3			V		
		bq29200		4.35					
V <sub>HYS</sub>	Overvoltage detection hysteresis			200	300	400	mV		
V <sub>OA</sub>	Overvoltage detection accuracy		T <sub>A</sub> = 25°C	−10			10	mV	
V <sub>OA_DRIFT</sub>	Overvoltage threshold temperature drift	T <sub>A</sub> = 0°C to 60°C		−0.4			0.4	mV/°C	
		T <sub>A</sub> = −40°C to 110°C		−0.6			0.6		
X <sub>DELAY</sub>	Overvoltage delay time scale factor	T <sub>A</sub> = 0°C to 60°C Note: Does not include external capacitor variation.		6			9	12	s/μF
		T <sub>A</sub> = −40°C to 110°C Note: Does not include external capacitor variation.		5.5			9	13.5	

## Electrical Characteristics (continued)

Typical values stated where  $T_A = 25^\circ\text{C}$  and  $V_{DD} = 7.2\text{ V}$ . Minimum and maximum values stated where  $T_A = -40^\circ\text{C}$  to  $110^\circ\text{C}$  and  $V_{DD} = 4\text{ V}$  to  $10\text{ V}$  (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
X <sub>DELAY_CTM</sub> <sup>(1)</sup>	Overvoltage delay time scale factor in Customer Test Mode		0.08			s/μF	
I <sub>CD(CHG)</sub>	Overvoltage detection charging current		150			nA	
I <sub>CD(DSG)</sub>	Overvoltage detection discharging current		60			μA	
V <sub>CD</sub>	Overvoltage detection external capacitor comparator threshold		1.2			V	
I <sub>CC</sub>	Supply current	(VC2–VC1) = (VC1–GND) = 3.5 V (See <a href="#">Figure 7.</a> )	3	6		μA	
V <sub>OUT</sub>	OUT pin drive voltage	(VC2–VC1) or (VC1–GND) > V <sub>PROTECT</sub> , VDD = 10 V, I <sub>OH</sub> = 0	6	8.25	9.5	V	
		(VC2–VC1) or (VC1–GND) = V <sub>PROTECT</sub> , VDD = V <sub>PROTECT</sub> , I <sub>OH</sub> = –100 μA, T <sub>A</sub> = 0°C to 60°C	1.75	2.5		V	
		(VC2–VC1) and (VC1–GND) < V <sub>PROTECT</sub> , I <sub>OL</sub> = 100 μA, T <sub>A</sub> = 25°C			200	mV	
		(VC2–VC1) and (VC1–GND) < V <sub>PROTECT</sub> , I <sub>OL</sub> = 0 μA, T <sub>A</sub> = 25°C		0	10	mV	
		VC2 = VC1 = VDD = 4 V, I <sub>OL</sub> = 100 μA			200	mV	
I <sub>OH</sub>	High-level output current	OUT = 1.75 V, (VC2–VC1) or (VC1–GND) = V <sub>PROTECT</sub> , VDD = V <sub>PROTECT</sub> to 10 V, T <sub>A</sub> = 0°C to 60°C	–100			μA	
I <sub>OL</sub>	Low-level output current	OUT = 0.05 V, (VC2–VC1) or (VC1–GND) < V <sub>PROTECT</sub> , VDD = V <sub>PROTECT</sub> to 10 V, T <sub>A</sub> = 0°C to 60°C	30			85	μA
I <sub>OH_ZV</sub>	High-level short-circuit output current	OUT = 0 V, (VC2–VC1) = (VC1–GND) = V <sub>PROTECT</sub> VDD = 4 to 10 V				–8	mA
I <sub>IN</sub>	Input current at VCx pins	Measured at VC1, (VC2–VC1) = (VC1–GND) = 3.5 V, T <sub>A</sub> = 0°C to 60°C (See <a href="#">Figure 7.</a> )	–0.2			0.2	μA
		Measured at VC2, (VC2–VC1) = (VC1–GND) = 3.5 V, T <sub>A</sub> = 0°C to 60°C (See <a href="#">Figure 7.</a> )				2.5	μA
V <sub>MM_DET_ON</sub>	Cell mismatch detection threshold for turning ON	(VC2–VC1) versus (VC1–GND) and vice-versa when cell balancing is enabled. VC2 = VDD = 7.6 V	17	30	45	mV	
V <sub>MM_DET_OFF</sub>	Cell mismatch detection threshold for turning OFF	Delta between (VC2–VC1) and (VC1–GND) when cell balancing is disabled. VC2 = VDD = 7.6 V	–9	0	9	mV	
V <sub>CB_EN_ON</sub>	Cell balance enable ON threshold	Active LOW pin at $\overline{\text{CB\_EN}}$				1	V
V <sub>CB_EN_OFF</sub>	Cell balance enable OFF threshold	Active HIGH at $\overline{\text{CB\_EN}}$	2.2			V	
I <sub>CB_EN</sub>	Cell balance enable ON input current	$\overline{\text{CB\_EN}}$ = GND (See <a href="#">Figure 8.</a> )				0.2	μA
R <sub>CB1</sub>	Internal cell balance switch resistance	$\overline{\text{CB\_EN}}$ = GND					Ω
R <sub>CB2</sub>	Internal cell balance switch resistance	$\overline{\text{CB\_EN}}$ = GND					Ω

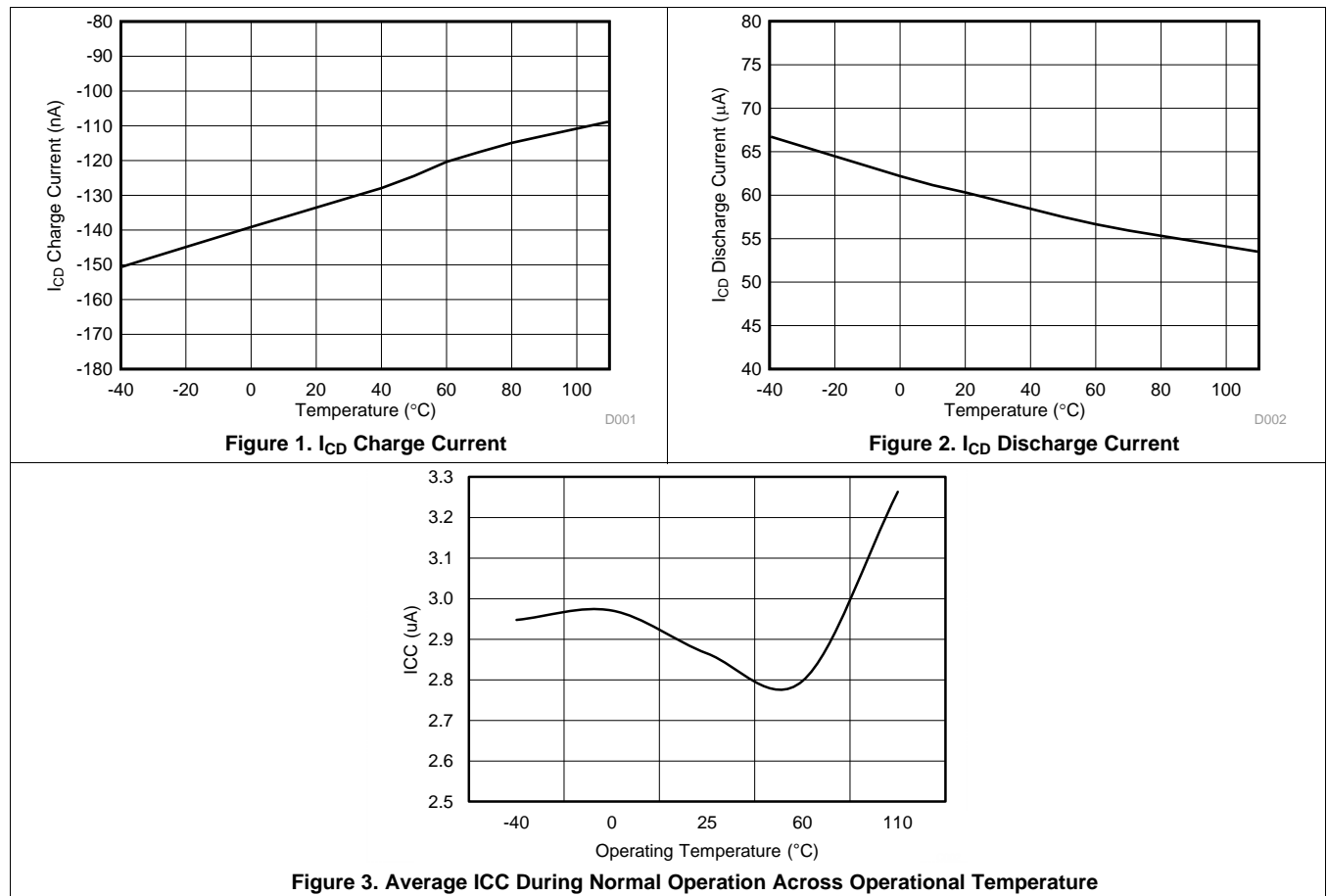
(1) Specified by design. Not 100% tested in production.

## 7.6 Recommended Cell Balancing Configurations

Typical values stated where  $T_A = 25^\circ\text{C}$  and  $(VC2-VC1)$ ,  $(VC1-GND) = 3.8\text{ V}$ . Minimum and maximum values stated where  $T_A = -40^\circ\text{C}$  to  $110^\circ\text{C}$ ,  $VDD = 4\text{ V}$  to  $10\text{ V}$ , and  $(VC2-VC1)$ ,  $(VC1-GND) = 3\text{ V}$  to  $4.2\text{ V}$ . All values assume recommended supply voltage filter resistance  $R_{VD}$  of  $100\ \Omega$  and 5% accurate or better cell balance resistor  $R_{CB}$ .

		MIN	NOM	MAX	UNIT
$I_{CB}$	Cell balance input current				
	$R_{CB} = 4700\ \Omega$	0.5	0.75	1	mA
	$R_{CB} = 2200\ \Omega$	1	1.5	2	
	$R_{CB} = 910\ \Omega$	2	3	4	
	$R_{CB} = 560\ \Omega$	3	4.5	6	
	$R_{CB} = 360\ \Omega$	3.5	6	8.5	
	$R_{CB} = 240\ \Omega$	4	7.5	11	
	$R_{CB} = 120\ \Omega$	5	10	15	

## 7.7 Typical Characteristics



## 8 Detailed Description

### 8.1 Overview

The bq2920x provides overvoltage protection and cell balancing for 2-series cell lithium-ion battery packs.

#### 8.1.1 Voltage Protection

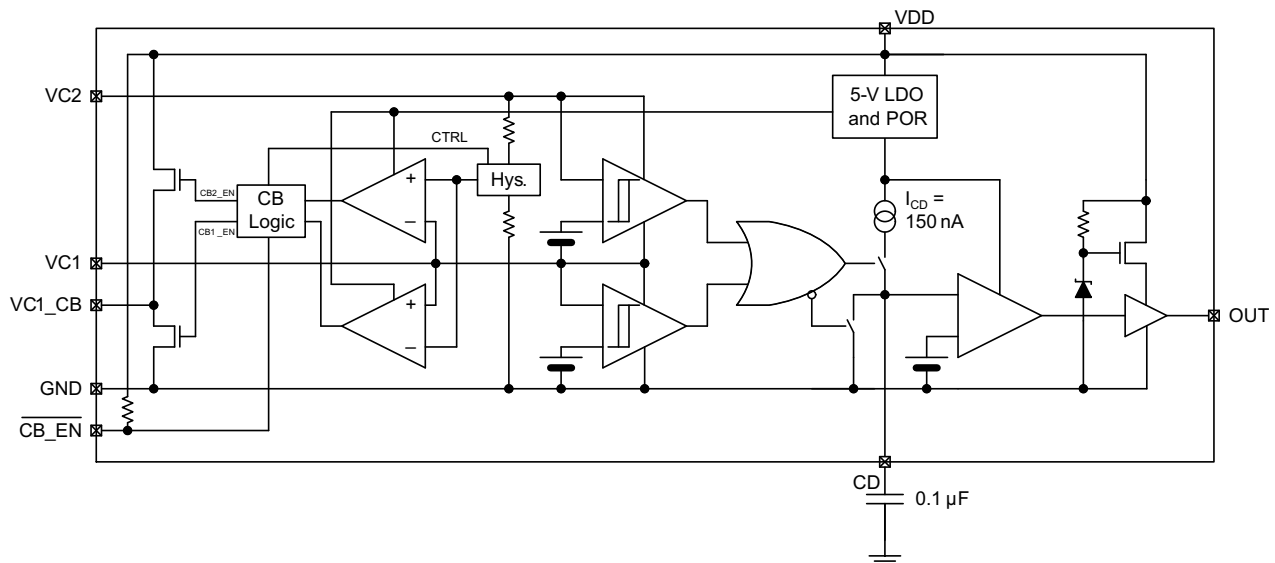
Each cell voltage is continuously compared to a factory configured internal reference threshold. If either cell reaches an overvoltage condition, the bq2920x device starts a timer that provides a delay proportional to the capacitance on the CD pin. Upon expiration of the internal timer, the OUT pin changes from a low to high state.

#### 8.1.2 Cell Balancing

If enabled, the bq2920x performs automatic cell-balance correction where the two cells are automatically corrected for voltage imbalance by loading the cell with the higher voltage with a small balancing current. When the cells are measured to be equal within nominally 0 mV, the load current is removed. It will be re-applied if the imbalance exceeds nominally 30 mV. The cell mismatch correction circuitry is enabled by pulling the CB\_EN pin low, and disabled when CB\_EN is pulled to greater than 2.2 V, for example, VDD.

If the internal cell balancing current of up to 15 mA is insufficient, the bq2920x may be configured via external circuitry to support much higher external cell balancing current.

### 8.2 Functional Block Diagram



### 8.3 Feature Description

#### 8.3.1 Protection (OUT) Timing

Sizing the external capacitor is based on the desired delay time as follows:

$$C_{CD} = \frac{t_d}{X_{DELAY}}$$

Where  $t_d$  is the desired delay time and  $X_{DELAY}$  is the overvoltage delay time scale factor, expressed in seconds per microFarad.  $X_{DELAY}$  is nominally 9 s/µF. For example, if a nominal delay of 3 seconds is desired, use a  $C_{CD}$  capacitor that is 3 s / 9 s/µF = 0.33 µF.

The delay time is calculated as follows:

$$t_d = C_{CD} \times X_{DELAY}$$



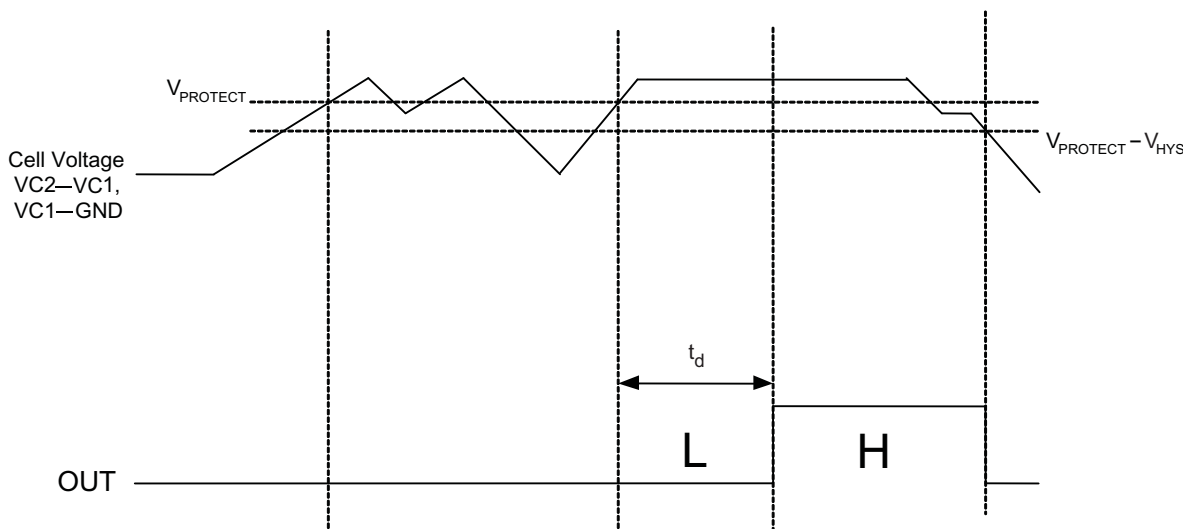
## Feature Description (continued)

If the cell overvoltage condition is removed before the external capacitor reaches the reference voltage, the internal current source is disabled and an internal discharge block is employed to discharge the external capacitor down to 0 V. In this instance, the OUT pin remains in a low state.

### 8.3.2 Cell Voltage > $V_{\text{PROTECT}}$

When one or both of the cell voltages rises above  $V_{\text{PROTECT}}$ , the internal comparator is tripped, and the delay begins to count to  $t_d$ . If the input remains above  $V_{\text{PROTECT}}$  for the duration of  $t_d$ , the bq2920x output changes from a low to a high state, by means of an internal pull-up network, to a regulated voltage of no more than 9.5 V when  $I_{\text{OH}} = 0$  mA.

The external delay capacitor should charge up to no more than the internal LDO voltage (approximately 5 V typically), and will fully discharge in approximately under 100 ms when the overvoltage condition is removed.



**Figure 4. Timing for Overvoltage Sensing**

### 8.3.3 Cell Connection Sequence

#### NOTE

Before connecting the cells, populate the overvoltage delay timing capacitor,  $C_{\text{CD}}$ .

The recommended cell connection sequence begins from the bottom of the stack, as follows:

1. GND
2. VC1
3. VC2

While not advised, connecting the cells in a sequence other than that described above does not result in errant activity on the OUT pin. For example:

1. GND
2. VC2 or VC1
3. Remaining VCx pin

### 8.3.4 Cell Balance Enable Control

To avoid prematurely discharging the cells, it is recommended to turn off (pull high) the active-low Cell Balance Enable Control pin at lower State of Charge (SOC) levels.

## Feature Description (continued)

### 8.3.5 Cell Balance Configuration

The cell balancing current may be calculated as follows:

For Cell 1 (VC1–GND) balancing current,  $I_{CB1}$ :

$$I_{CB1} = \frac{VC1}{R_{CB} + R_{CB1}} \quad (1)$$

For Cell 2 (VC2–VC1) balancing current,  $I_{CB2}$ :

$$I_{CB2} = \frac{(VC2 - VC1)}{(R_{CB} + R_{VD}) + R_{CB2}} \quad (2)$$

Where:

$R_{CB}$  = resistor connected between the top of Cell 1 and the VC1\_CB

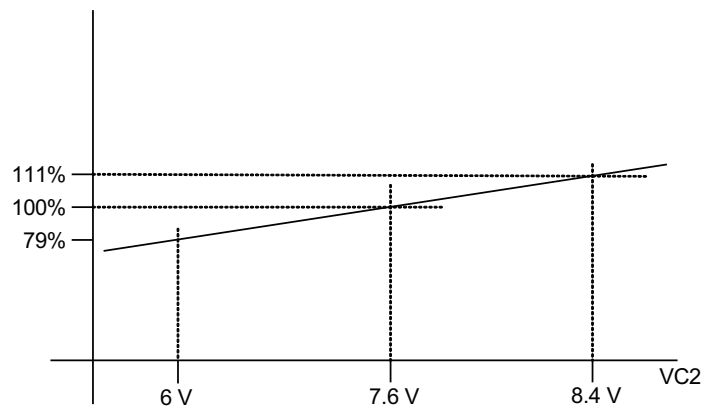
$R_{CB1}$  = resistor connected between the top of Cell 1 and the VC1

$R_{CB2}$  = resistor connected between the top of Cell 2 and the VC2

$R_{VD}$  = resistor connected between the top of Cell 2 and the VDD

### 8.3.6 Cell Imbalance Auto-Detection (Via Cell Voltage)

The  $V_{MM\_DET\_ON}$  and  $V_{MM\_DET\_OFF}$  specifications are calibrated where  $VDD = VC2 = 7.6$  V and  $VC1 = 3.8$  V. The recommended range of cell balancing is  $VC2$  and  $VDD$  between 6.0 V and 8.4 V, and  $VC1$  between 3 V and 4.2 V. Below  $VDD = 6$  V, it is recommended to pull  $\overline{CB\_EN}$  high to disable the cell balancing function.



**Figure 5.  $V_{MM\_DET\_ON}$  and  $V_{MM\_DET\_OFF}$  Threshold**

### 8.3.7 Customer Test Mode

Customer Test Mode (CTM) helps to greatly reduce the overvoltage detection delay time and enable quicker customer production testing. This mode is intended for quick-pass board-level verification tests, and, as such, individual cell overvoltage levels may deviate slightly from the specifications ( $V_{PROTECT}$ ,  $V_{OA}$ ). If accurate overvoltage thresholds are to be tested, use the standard delay settings that are intended for normal use.

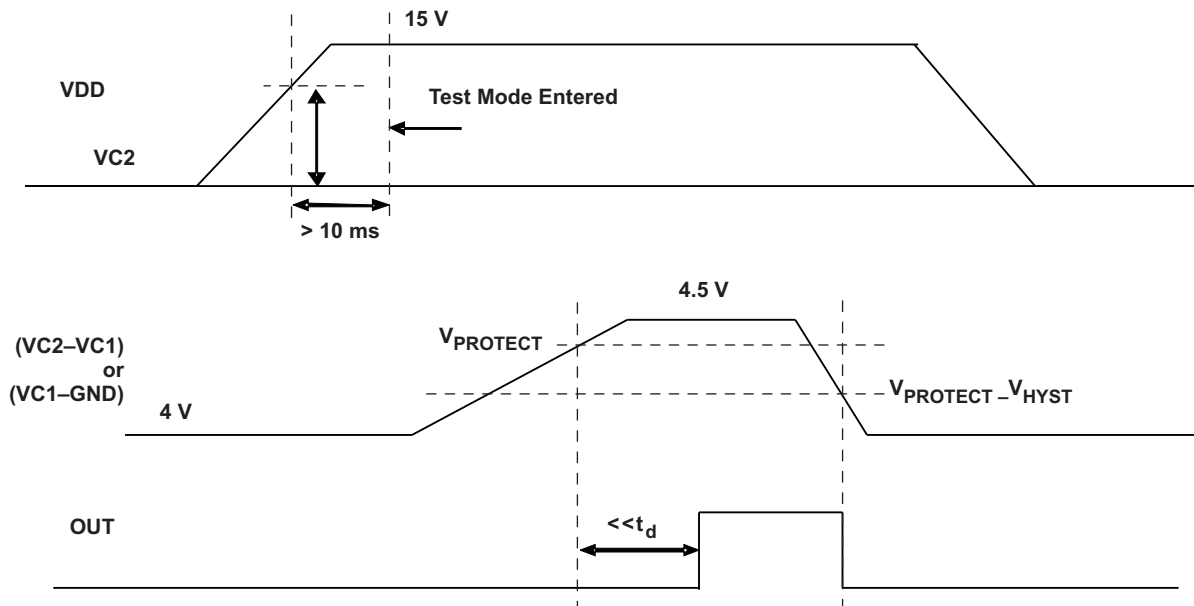
To enter CTM,  $VDD$  should be set to approximately 9.5 V higher than  $VC2$ . When CTM is entered, the device switches from the normal overvoltage delay time scale factor,  $X_{DELAY}$ , to a significantly reduced factor of approximately 0.08, thereby reducing the delay time during an overvoltage condition.

## Feature Description (continued)

### CAUTION

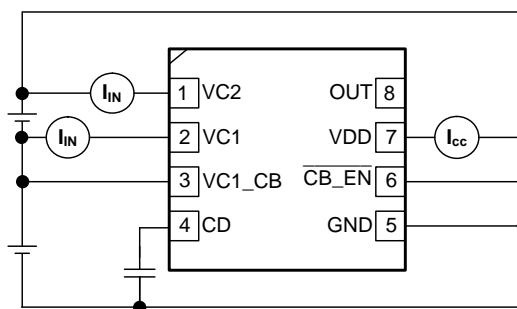
Avoid exceeding any Absolute Maximum Voltages on any pins when placing the part into CTM. Also, avoid exceeding absolute maximum voltages for the individual cell voltages (VC1–GND) and (VC2–VC1). Stressing the pins beyond the rated limits may cause permanent damage to the device.

To exit CTM, power off the device and then power it back on.



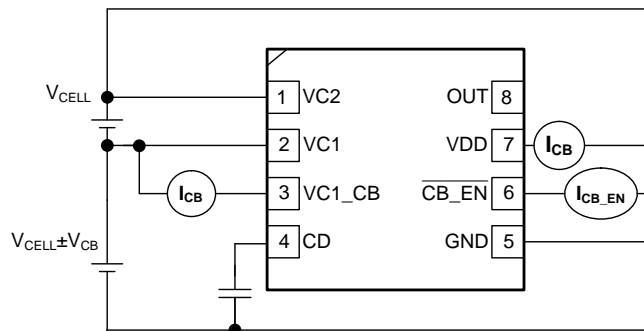
**Figure 6. Voltage Test Limits**

### 8.3.8 Test Conditions



**Figure 7.  $I_{CC}$ ,  $I_{IN}$  Measurement**

## Feature Description (continued)



**Figure 8.  $I_{CB}$  Measurement**

## 8.4 Device Functional Modes

This device monitors the voltage of the cells connected to the VCx pins and depending on these voltages and the overall battery voltage at VDD the device enters different operating modes.

### 8.4.1 NORMAL Mode

The device is operating in NORMAL mode when the cell voltage range is between the over-charge detection threshold ( $V_{PROTECT}$ ) and the minimum supply voltage.

If this condition is satisfied, the device turns OFF the OUT pin.

### 8.4.2 PROTECTION Mode

The device is operating in PROTECTION mode when the cell over voltage protection feature has been triggered. See [Cell Voltage >  \$V\_{PROTECT}\$](#)  for more details on this feature.

If this condition is satisfied, the device turns ON the OUT pin.

## 9 Application and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

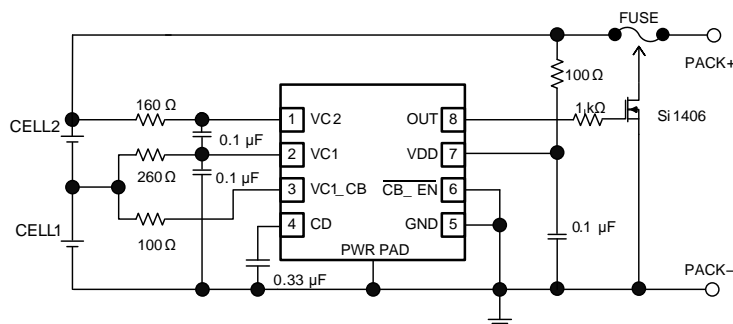
### 9.1 Application Information

The bq2920x is designed to be used in 2-series Li-Ion battery packs and with the option to include voltage-based cell balancing. The number of parallel cells or the overall capacity of the battery only affects the cell balancing circuit due to the level of potential imbalance that needs to be corrected.

### 9.2 Typical Applications

#### 9.2.1 Battery Connection

Figure 9 shows the configuration for the 2-series cell battery connection with cell balancing enabled.



**Figure 9. 2-Series Cell Configuration**

#### 9.2.1.1 Design Requirements

For this design example, use the parameters listed in Table 1.

**Table 1. Design Parameters**

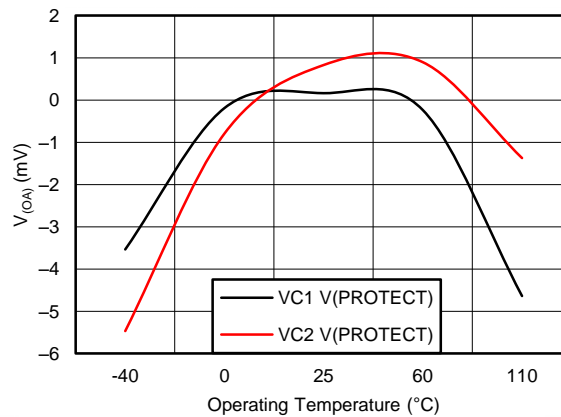
DESIGN PARAMETER	EXAMPLE VALUE at T <sub>A</sub> = 25°C
Input voltage range	4 V to 10 V
Overvoltage Protection (OVT)	4.35 V
Overvoltage detection delay time	3 s
Overvoltage detection delay timer capacitor	0.33 μF
Cell Balancing Enabled	Yes
Cell Balancing Current, ICB1 and ICB2	10 mA
Cell Balancing Resistors, RCB, RCB1, RCB2 and RVD	RCB = 100 Ω, RCB1 = 260 Ω, RCB2 = 160 Ω, RVD = 100 Ω

#### 9.2.1.2 Detailed Design Procedure

The bq2920x has limited features but there are some key calculations to be made when selecting external component values.

- Calculate the required CCD capacitor value for the voltage protection delay time. Care should be taken to evaluate the tolerances of the capacitor and the bq2920x to ensure system specifications are met.
- Calculate the cell balancing resistor values to provide a suitable level of balancing current that will, at a minimum, counter act an increase in imbalance during normal operation of the battery. Care should be taken to ensure any connectivity resistance is also considered as this will also reduce the balancing current level.

### 9.2.1.3 Application Curve

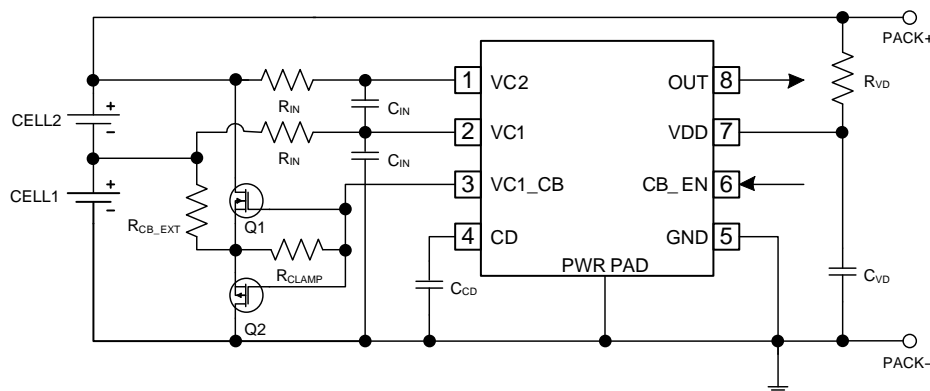


**Figure 10. Average  $V_{\text{PROTECT}}$  Accuracy ( $V_{\text{OA}}$ ) Across Operation Temperature**

## 9.3 System Example

### 9.3.1 External Cell Balancing

Higher cell balancing currents can be supported by means of a simple external network, as shown in [Figure 11](#).



**Figure 11. External Cell Balancing Configuration**

$R_{\text{CLAMP}}$  ensures that both Q1 and Q2 remain off when balancing is disabled, and should be sized above 2 k $\Omega$  to prevent excessive internal device current when the balancing network is activated.  $R_{\text{CB\_EXT}}$  determines the value of the balancing current, and is dependent on the voltage of the balanced cell, as follows:

$$I_{\text{bal}} = \frac{V_{\text{CELL}}}{R_{\text{CB\_EXT}}}$$

## 10 Power Supply Recommendations

The recommended power supply for this device is a maximum 10-V operation on the VDD input pin.


## 11 Layout


### 11.1 Layout Guidelines

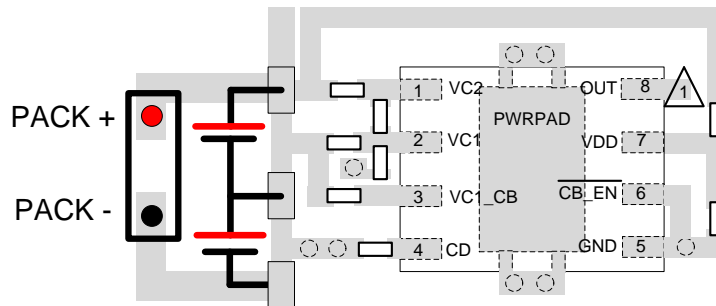
The following are the recommended layout guidelines:

1. Ensure the input filters to the VC1 and VC2 pins are as close to the IC as possible to improve noise immunity.
2. If the OUT pin is used to control a high current path, for example: to blow a chemical fuse, then care should be taken to ensure the high current path creates minimal interference of the bq2920x voltage sense inputs.
3. The input RC filter on the VDD pin should be close to the terminal of the IC.

### 11.2 Layout Example

 Additional circuitry required based on usage of the OUT pin

 Via connects between two layers



## 12 Device and Documentation Support

### 12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

**Table 2. Related Links**

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
bq29200	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
bq29209	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>

### 12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 12.3 Trademarks

E2E is a trademark of Texas Instruments.  
All other trademarks are the property of their respective owners.

### 12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 12.5 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



## PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">BQ29200DRBR</a>	Active	Production	SON (DRB)   8	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	200
BQ29200DRBR.A	Active	Production	SON (DRB)   8	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	200
BQ29200DRBR.B	Active	Production	SON (DRB)   8	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	200
<a href="#">BQ29200DRBT</a>	Active	Production	SON (DRB)   8	250   SMALL T&R	Yes	Call TI   Nipdau	Level-2-260C-1 YEAR	-40 to 85	200
BQ29200DRBT.A	Active	Production	SON (DRB)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	200
BQ29200DRBT.B	Active	Production	SON (DRB)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	200
<a href="#">BQ29209DRBR</a>	Active	Production	SON (DRB)   8	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	209
BQ29209DRBR.A	Active	Production	SON (DRB)   8	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	209
<a href="#">BQ29209DRBT</a>	Active	Production	SON (DRB)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	209
BQ29209DRBT.A	Active	Production	SON (DRB)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	209
BQ29209DRBT.B	Active	Production	SON (DRB)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	209
BQ29209DRBTG4	Active	Production	SON (DRB)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	209
BQ29209DRBTG4.A	Active	Production	SON (DRB)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	209
BQ29209DRBTG4.B	Active	Production	SON (DRB)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	209

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF BQ29209 :**

- Automotive : [BQ29209-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

## TAPE AND REEL INFORMATION



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ29200DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ29200DRBT	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ29209DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ29209DRBT	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ29209DRBTG4	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BQ29200DRBR	SON	DRB	8	3000	346.0	346.0	33.0
BQ29200DRBT	SON	DRB	8	250	210.0	185.0	35.0
BQ29209DRBR	SON	DRB	8	3000	346.0	346.0	33.0
BQ29209DRBT	SON	DRB	8	250	210.0	185.0	35.0
BQ29209DRBTG4	SON	DRB	8	250	210.0	185.0	35.0

**DRB 8**

**GENERIC PACKAGE VIEW**

**VSON - 1 mm max height**

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

4203482/L



## PACKAGE OUTLINE

**VSON - 1 mm max height**

PLASTIC SMALL OUTLINE - NO LEAD



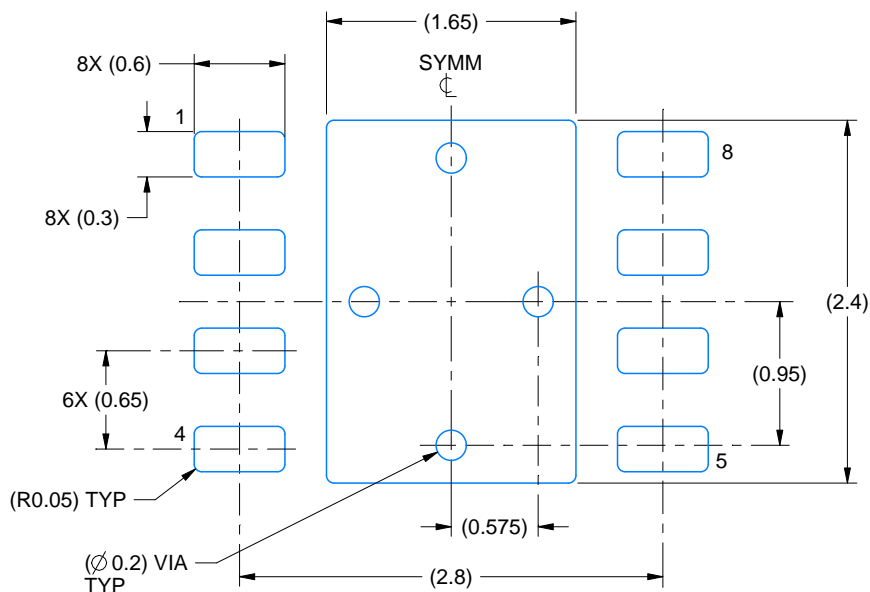
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

# EXAMPLE BOARD LAYOUT

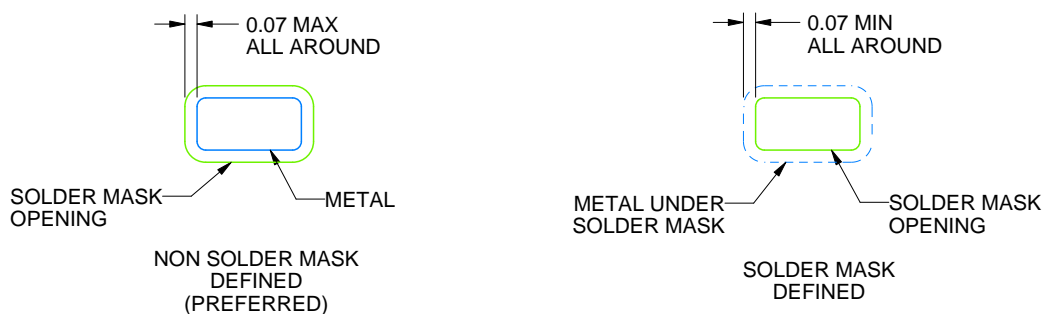
DRB0008B

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE  
SCALE:20X



SOLDER MASK DETAILS

4218876/A 12/2017

NOTES: (continued)

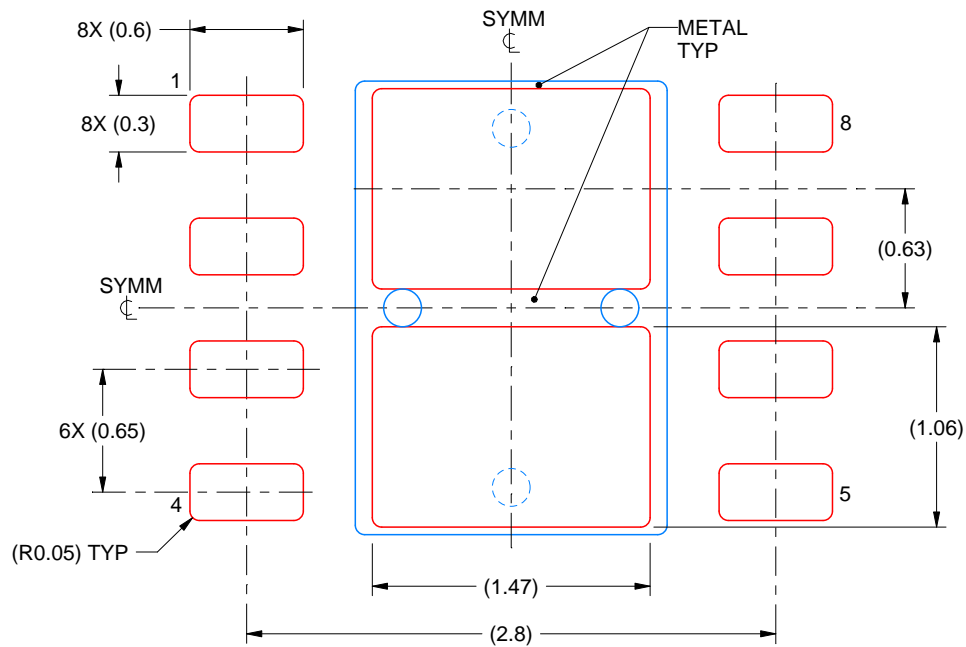
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

# EXAMPLE STENCIL DESIGN

DRB0008B

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD  
81% PRINTED SOLDER COVERAGE BY AREA  
SCALE:25X

4218876/A 12/2017

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265  
Copyright © 2025, Texas Instruments Incorporated